



Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638
 Phone: (562) 404-4474 * Fax: (562) 404-1773
 ssdi@ssdi-power.com * www.ssdi-power.com

SPD4942 Thru SPD4948 Series

1 Amp, 150-200 nsec, 200-1000 V Fast Recovery Rectifier

Designer's Data Sheet

Part Number/Ordering Information^{1/}

SPD **---** **---** **---**

L **Screening^{2/}**
 --- = Not Screened
 TX = TX Level
 TXV = TXV
 S = S Level (for SM, use -S)
Package Type
 --- = Axial Leaded
 SM = Surface Mount Round Tab
 SMS = Surface Mount Square Tab

Voltage

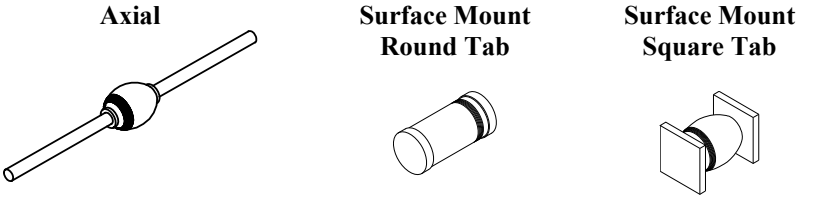
4945 = 500V	4946 = 600V
4942 = 200V	4947 = 800V
4943 = 300V	4948 = 1000V
4944 = 400V	

- Features:**
- Fast Recovery: 150-200 nsec maximum
 - Low Reverse Leakage Current
 - Single Chip Construction
 - PIV to 1000 Volts
 - Hermetically Sealed
 - High Surge Rating
 - Low Thermal Resistance
 - Replacement for 1N4942 – 1N4948
 - TX, TXV, and Space Level Screening Available^{2/}

Maximum Ratings	Symbol	Value	Units	
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SPD4942	200	Volts	
	SPD4943	300		
	SPD4944	400		
	SPD4945	500		
	SPD4946	600		
	SPD4947	800		
	SPD4948	1000		
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A = 25 °C)	I_O	1	Amps	
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on I _O , allow junction to reach equilibrium between pulses, T _A = 25 °C)	I_{FSM}	25	Amps	
Operating & Storage Temperature	T_{OP} & T_{STG}	-65 to +175	°C	
Maximum Thermal Resistance	Junction to Leads, L= 3/8"	R_{θJL}	45	°C/W
	Junction to Tabs	R_{θJE}	35	

NOTES:

- ^{1/} For Ordering Information, Operating Curves, Price, and Availability- Contact Factory.
^{2/} Screening Based on MIL-PRF-19500. Screening Flows Available on Request.





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Electrical Characteristics	Symbol	Value	Units
Instantaneous Forward Voltage Drop ($I_F = 1\text{Adc}$, $T_A = 25\text{ }^\circ\text{C}$, 300 μs Pulse)	V_F	1.3	V_{DC}
Instantaneous Forward Voltage Drop ($I_F = 1\text{Adc}$, $T_A = -55\text{ }^\circ\text{C}$, 300 μs Pulse)	V_F	1.5	V_{DC}
Reverse Leakage Current (Rated V_R , $T_A = 25\text{ }^\circ\text{C}$, 300 μs minimum pulse)	I_R	1.0	μA
Reverse Leakage Current (Rated V_R , $T_A = 100\text{ }^\circ\text{C}$, 300 μs minimum pulse)	I_R	20	μA
Reverse Recovery Time ($I_F = 500\text{ mA}$, $I_R = 1\text{ Amp}$, $I_{RR} = 250\text{ mA}$, $T_A = 25\text{ }^\circ\text{C}$)	t_{RR}	150	nsec
		200	
Junction Capacitance ($V_R = 10V_{DC}$, $T_A = 25\text{ }^\circ\text{C}$, $f = 1\text{MHz}$)	C_J	20	pF

**CASE OUTLINE:
Axial**

Dimensions		
DIM	MIN	MAX
A	.100"	.150"
B	---	.180"
C	.027"	.033"
D	1.00"	---

**CASE OUTLINE:
Surface Mount Round Tab**

Dimensions		
DIM	MIN	MAX
A	.095"	.105"
B	.185"	.205"
C	.015"	.035"

**CASE OUTLINE:
Surface Mount Square Tab**

Dimensions		
DIM	MIN	MAX
A	.134"	.153"
B	.200"	.280"
C	.022"	.028"
D	.002"	---